# MG6404WZ

#### 650V 40A Insulated Gate Bipolar Transistor

Datasheet

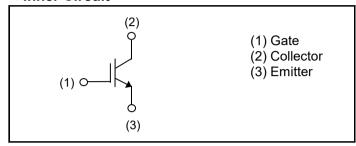
V <sub>CES</sub>	650V
I <sub>C (Nominal)</sub>	40A
V <sub>CE(sat) (Typ.)</sub>	1.5V
Max. Possible Chips per Wafer	827pcs

# ● Outline Wafer

#### Features

- 1) Trench Light Punch Through Type
- 2) Low Collector Emitter Saturation Voltage
- 3) High Speed Switching & Low Switching Loss
- 4) Short Circuit Withstand Time 2µs

#### ●Inner Circuit



#### Application

Solar Inverter

**UPS** 

Welding

ΙH

**PFC** 

Absolute Maximum Ratings

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Parameter	Symbol	Value	Unit		
Collector - Emitter Voltage, T <sub>j</sub> = 25°C	$V_{CES}$	650	V		
Gate - Emitter Voltage	$V_{GES}$	±30	V		
Collector Current	I <sub>C</sub> <sup>*1</sup>	*1)	Α		
Pulsed Collector Current	I <sub>CP</sub> *2	160	А		
Operating Junction Temperature	T <sub>j</sub>	-40 to +175	°C		

<sup>\*1</sup> Depending on thermal properties of assembly

<sup>\*2</sup> Pulse width limited by  $T_{jmax.}$ 

## ●Design Assurance

Parameter	Symbol	Conditions		Values		Unit
raiailletei	Symbol	Conditions	Min.	Тур.	Max.	Offic
		$V_{CC} \le 360V$ ,				
Short Circuit Withstand Time	t <sub>sc</sub> *3	$V_{CC} \le 360V$ , $V_{GE} = 15V$ , $T_i = 25^{\circ}C$	2	-	-	μs
		T <sub>j</sub> = 25°C				
		$I_C = 160A, V_{CC} = 520V,$				
Reverse Bias Safe Operating Area	RBSOA*3	$I_C = 160A$ , $V_{CC} = 520V$ , $V_P = 650V$ , $V_{GE} = 15V$ , $R_G = 100\Omega$ , $T_j = 175^{\circ}C$	FULL SQUARE		-	
		$R_G = 100\Omega, T_j = 175^{\circ}C$				

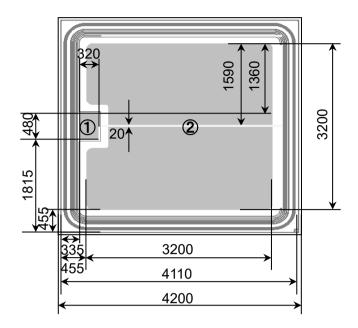
<sup>\*3</sup> Design assurance without measurement

# ●Electrical Characteristics (at T<sub>i</sub> = 25°C unless otherwise specified, in case of TO-247N package)

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Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector - Emitter Breakdown Voltage	BV <sub>CES</sub>	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	1	-	٧
Collector Cut - off Current	I <sub>CES</sub>	$V_{CE} = 650V, V_{GE} = 0V$	-	-	10	μΑ
Gate - Emitter Leakage Current	I <sub>GES</sub>	$V_{GE} = \pm 30V$ , $V_{CE} = 0V$	-	ı	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 27.5 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V <sub>CE(sat)</sub> *3	$I_{C} = 40A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.5 1.85	1.9 -	V
Input Capacitance	C <sub>ies</sub>	V <sub>CE</sub> = 30V,	-	2370	-	
Output Capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0V,	-	94	-	pF
Reverse transfer Capacitance	$C_{res}$	f = 1MHz	-	38	-	
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 400V,	-	81	-	
Gate - Emitter Charge	$Q_ge$	I <sub>C</sub> = 40A,	-	17	-	nC
Gate - Collector Charge	$Q_gc$	V <sub>GE</sub> = 15V	-	31	-	

<sup>\*3</sup> Design assurance without measurement

## **●Chip Information**



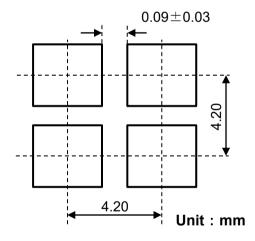
Unit: µm

: Pad Area

① : Gate Bonding Pad

② : Emitter Bonding Pad

Backside: Collector



Wafer Size	150mm
Wafer Thickness	0.07±0.01mm
Chip Size	4.20mm×4.20mm
Cut Line Width	0.09±0.03mm
Top Side Metallization	AlSiCu:4.4µm
Back Side Metallization	Ti/Ni:0.4µm/Au:0.05µm
Passivation	Polyimide

#### •Further Electrical Characteristics

Switching characteristics and thermal properties are depending strongly on module design and mounting technology and can therefore not be specified for a bare die.

This chip data sheet refers to the device data sheet	RGTV80TS65

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